



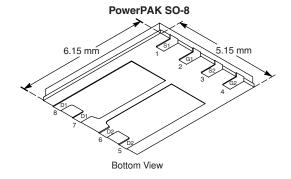
Dual N-Channel 60-V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)	Q _g (Typ.)		
60	0.023 at V _{GS} = 10 V	9.6	43		

FEATURES

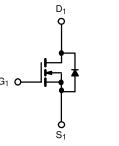
- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET[®] Power MOSFET
- New Low Thermal Resistance PowerPAK[®] Package
- Dual MOSFET for Space Savings
- 100 % R_g Tested
- · High Threshold Voltage at High Temperature



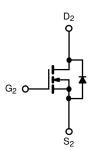


Ordering Information: Si7964DP-T1-E3 (Lead (Pb)-free)

Si7964DP-T1-GE3 (Lead (Pb)-free and Halogen-free)



N-Channel MOSFET



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	T _A = 25 °C, unle	ss otherwise n	oted			
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V_{DS}	60		V	
Gate-Source Voltage		V_{GS}	± 20			
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 25 °C	I_	9.6	6.1		
Continuous Diairi Current (1 j = 150 °C)	T _A = 70 °C	- I _D	7.7	4.9		
Pulsed Drain Current		I _{DM}	40		Α	
Continuous Source Current (Diode Conduction) ^a		I _S	2.9	1.2		
Single Avalanche Current	L = 0.1 mH	I _{AS}	25			
Single Avalanche Energy		E _{AS}	31		mJ	
Maximum Dougs Dissinational	T _A = 25 °C	P _D	3.5	1.4	w	
Maximum Power Dissipation ^a	T _A = 70 °C	' D	2.2	0.9		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	
Soldering Recommendations (Peak Temperature)b, c		,	260			

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Marrian and Luncking to Aughton to	t ≤ 10 s	R _{thJA}	26	35	°C/W
Maximum Junction-to-Ambient ^a	Steady State		60	85	
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	2.2	2.7	

Notes:

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (http://www.vishay.com/ppg?73257). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

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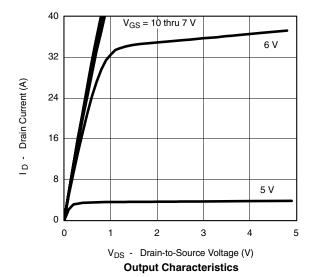
SPECIFICATIONS T _J = 25 °C, unless otherwise noted								
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit		
Static			-					
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	3.4		4.5	V		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA		
Zana Oata Walkana Busin Oamani	I _{DSS}	V _{DS} = 60 V, V _{GS} = 0 V	30 V, V _{GS} = 0 V		1	μΑ		
Zero Gate Voltage Drain Current		V _{DS} = 60 V, V _{GS} = 0 V, T _J = 55 °C			5			
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			Α		
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 10 \text{ V}, I_D = 9.6 \text{ A}$		0.019	0.023	Ω		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 9.6 A		30		S		
Diode Forward Voltage ^a	V_{SD}	I _S = 2.9 A, V _{GS} = 0 V		0.8	1.2	V		
Dynamic ^b								
Total Gate Charge	Q_g	Q_{g}		43	65			
Gate-Source Charge	Q _{gs}	$V_{DS} = 30 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 9.6 \text{ A}$		15		nC		
Gate-Drain Charge	Q_{gd}			8.5				
Gate Resistance	R_{g}	f = 1 MHz	1	2	3	Ω		
Turn-On Delay Time	t _{d(on)}			20	30			
Rise Time	t _r	V_{DD} = 20 V, R_L = 20 Ω		15	25	ns		
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ 1 A, V_{GEN} = 10 V, R_g = 6 Ω		50	75			
Fall Time	t _f			15	25			
Source-Drain Reverse Recovery Time	t _{rr}	$I_F = 2.9 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}$		35	60			

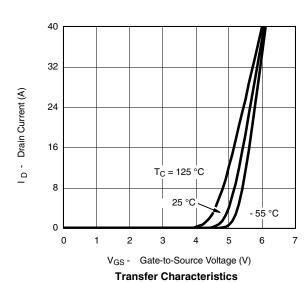
Notes:

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



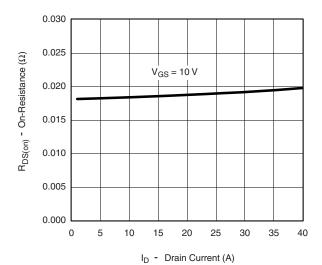




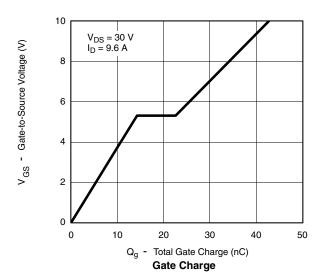


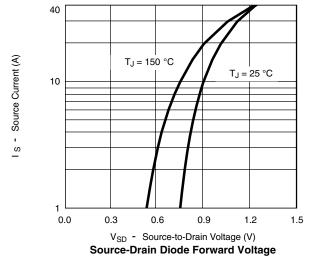


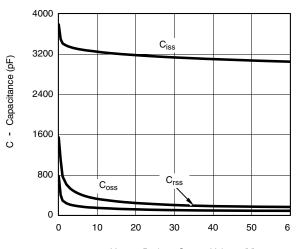
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



On-Resistance vs. Drain Current

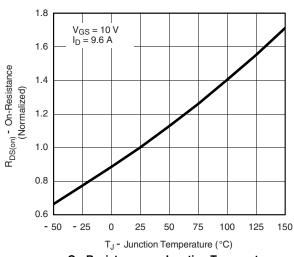




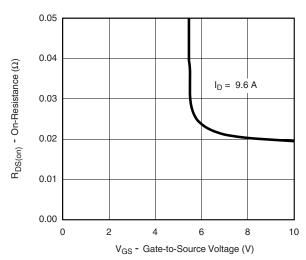


V_{DS} - Drain-to-Source Voltage (V)

Capacitance



On-Resistance vs. Junction Temperature

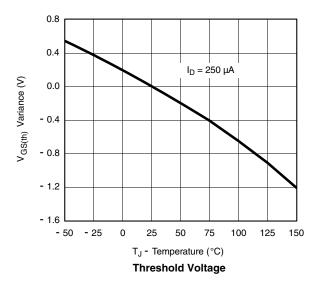


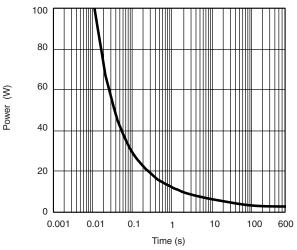
On-Resistance vs. Gate-to-Source Voltage

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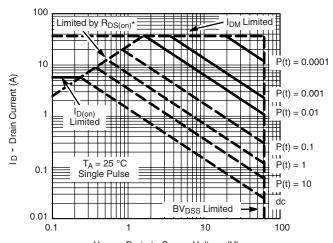
VISHAY

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



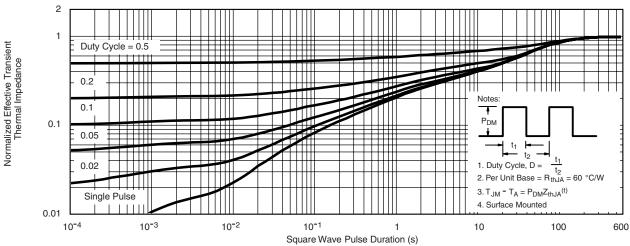


Single Pulse Power



 $\label{eq:VDS} V_{DS} - Drain-to-Source Voltage (V) $$^*V_{GS}$ > minimum V_{GS} at which $R_{DS(on)}$ is specified$

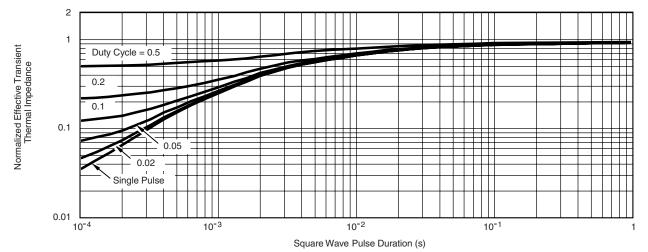
Safe Operating Area, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

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